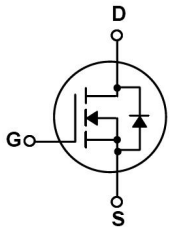
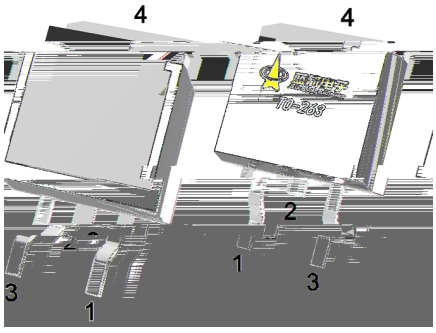
TO-263 N

N-CHANNEL MOSFET in a TO-263 Plastic Package.

High frequency switching and synchronous rectification,BMS,Motor, Meet the stringent requirements of automotive applications.





PIN1 G PIN 2 4 D PIN 3 S

See Marking Instructions.

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V_{DSS}	100	V
Drain Current		I_D(Tc=25℃)	180	A
Pulsed Drain Current		I_{DM}	385	A
Gate-Source Voltage		V_{GS}	±20	V
Single Pulsed Avalanche Energy(L=0.5mH)		E_{AS}	563	mJ
Avalanche Current		I_{AS}	37.5	A
Total Power Dissipation		P_D(Tc=25℃)	237	W
Junction and Storage Temperature Range		T_J,T_{STG}	-55 to 150	
Thermal Resistance-Junction to Ambient	t≤10s	$R_{\theta JA}$	17.7	/W
	Steady-State		70.7	
Thermal Resistance-Junction to Case	Steady-State	$R_{\theta JC}$	0.53	

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V I_D=250μA	100	112		V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=100V V_{GS}=0V			1	μA
Gate-Body Leakage Current Forward	I_{GSS}	V_{GS}=±20V V_{DS}=0V			±100	nA
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS} I_D=250μA	2	2.9	4	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	V_{GS}=10V I_D=20A		3.5	4.0	mΩ
Forward On Voltage	V_{SD}	V_{GS}=0V I_S=1A			1.2	V
Gate resistance	R_g	f=1MHz		1.7		Ω
Input Capacitance	C_{iss}	V_{DS}=25V V_{GS}=0V f=1MHz		5550		pF
Output Capacitance	C_{oss}			2050		
Reverse Transfer Capacitance	C_{rss}			180		
Total Gate Charge	$Q_{g(10V)}$	V_{GS}=10V, V_{DS}=50V, I_D=20A		80		nC
Gate Source Charge	Q_{gs}			23		
Gate Drain Charge	Q_{gd}			17		

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Turn-On Delay Time	$t_{d(on)}$	V_{GS}=10V V_{DS}=50V R_L=2.5Ω R_{GEN}=3Ω		25		ns
Turn-On Rise Time	t_r			17		
Turn-Off Delay Time	$t_{d(off)}$			53		
Turn-Off Fall Time	t_f			24		

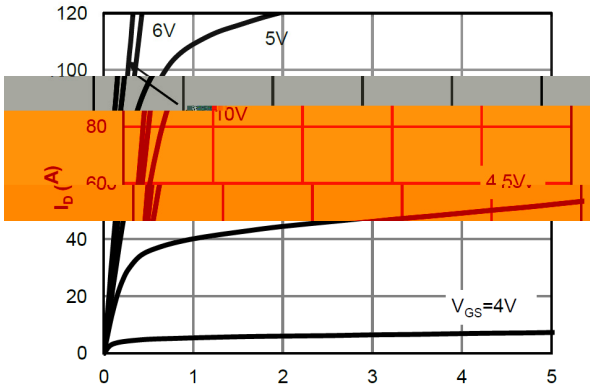


Figure 1: On-Region Characteristics

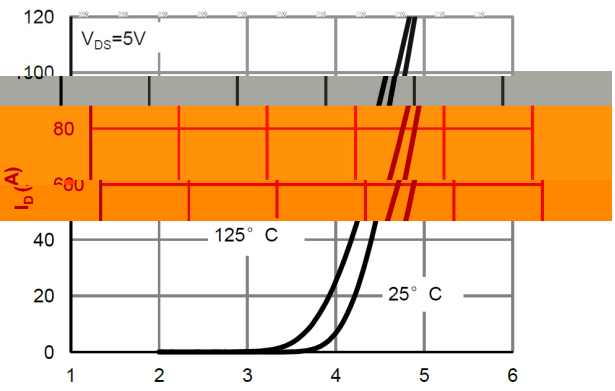


Figure 2: Transfer Characteristics

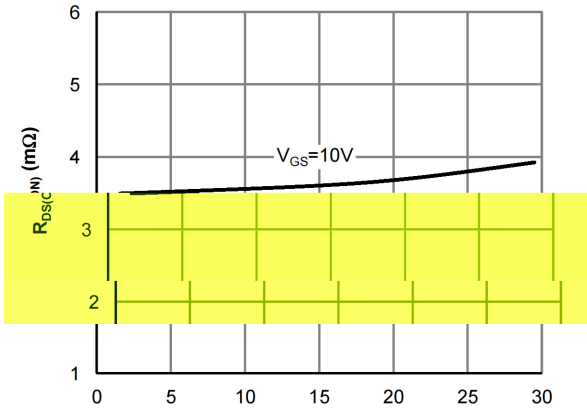


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

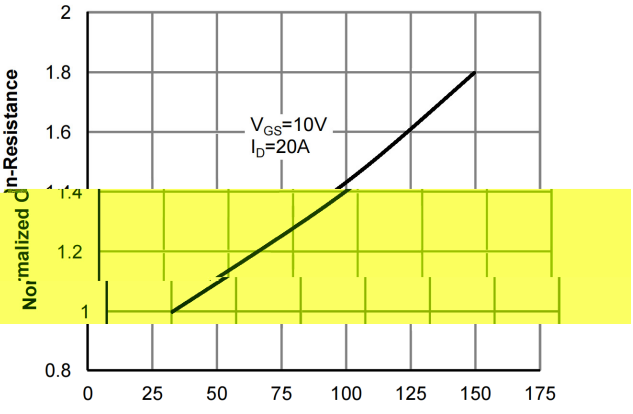


Figure 4: On-Resistance vs. Junction Temperature

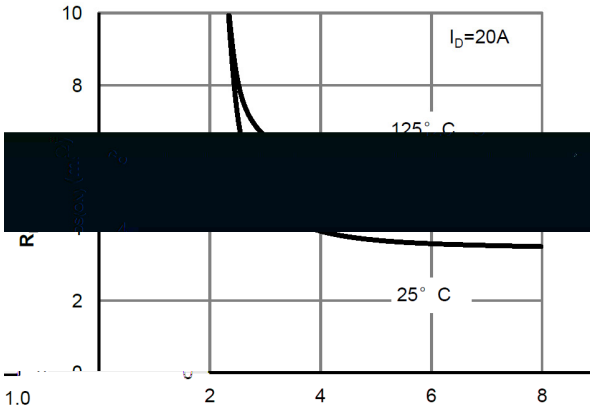


Figure 5: On-Resistance vs. Gate-Source Voltage

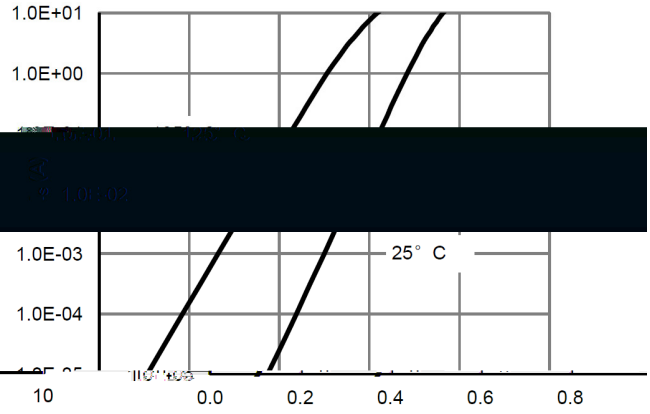


Figure 6: Body-Diode Characteristics

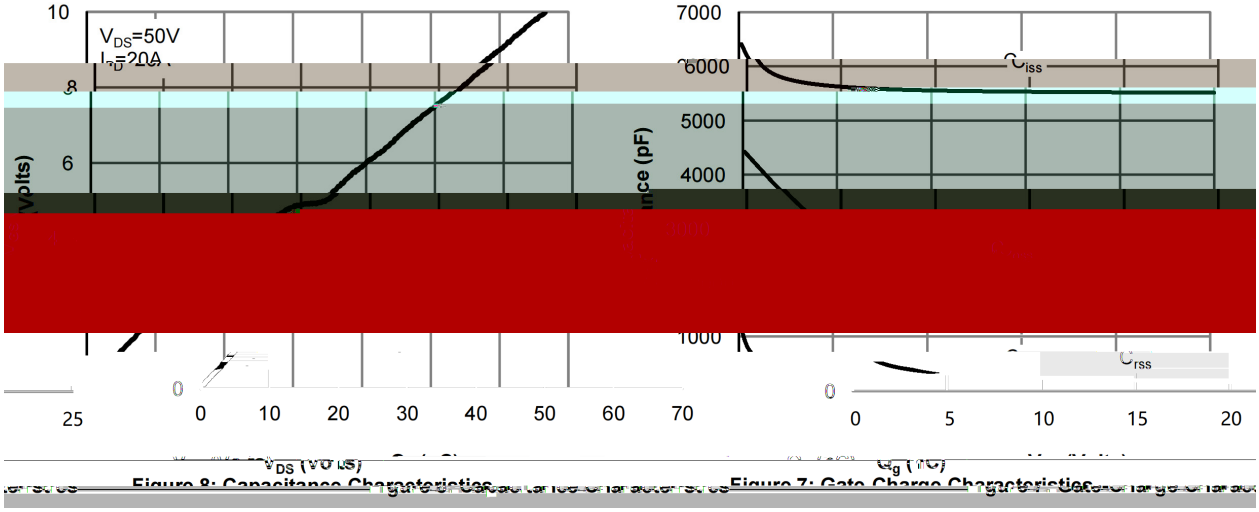


Figure 8: Capacitance Characteristics

Figure 7: Gate Charge Characteristics

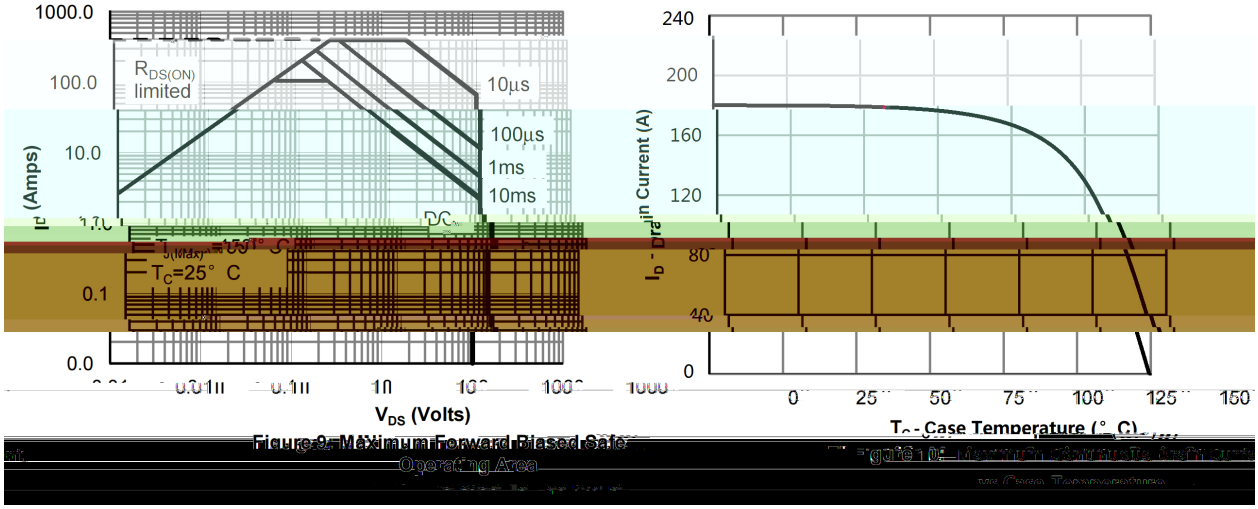


Figure 9: Maximum Forward Biased Safe Operating Area

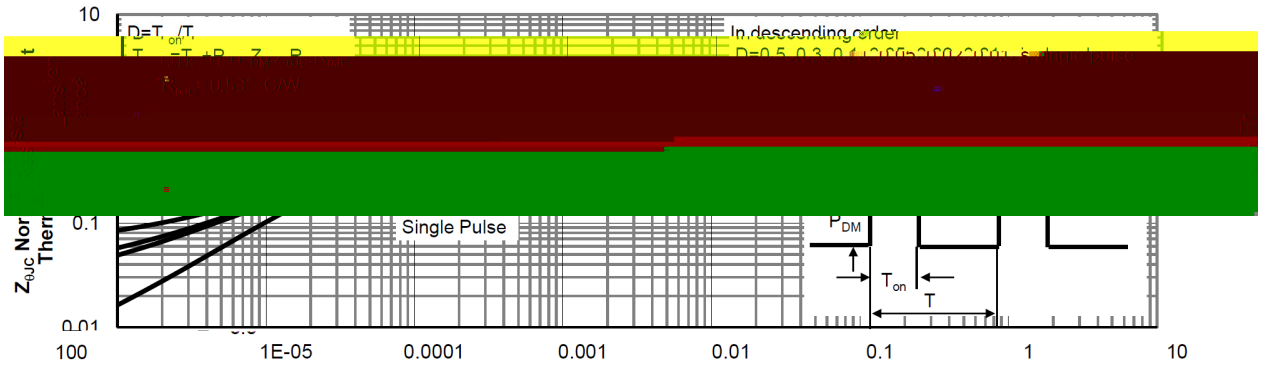
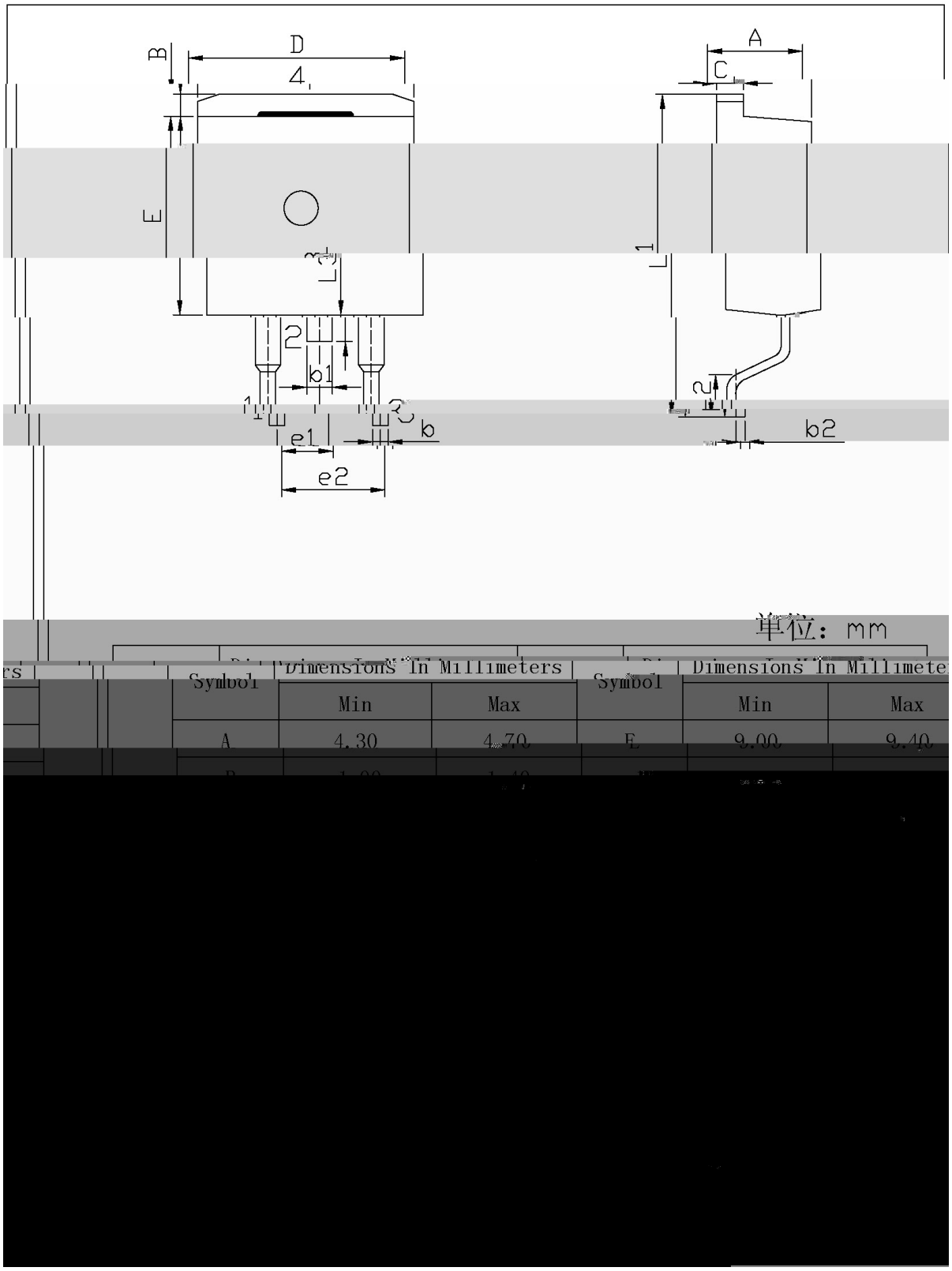
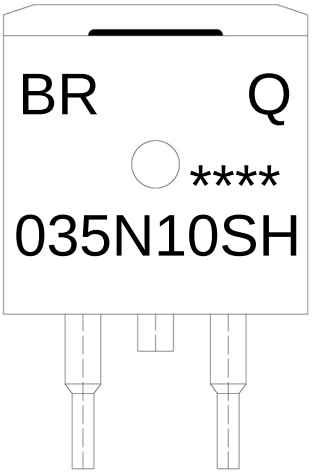


Figure 11: Normalized Maximum Transient Thermal Impedance



单位：mm

Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min	Max		Min	Max
A	4.30	4.70	E	9.00	9.40

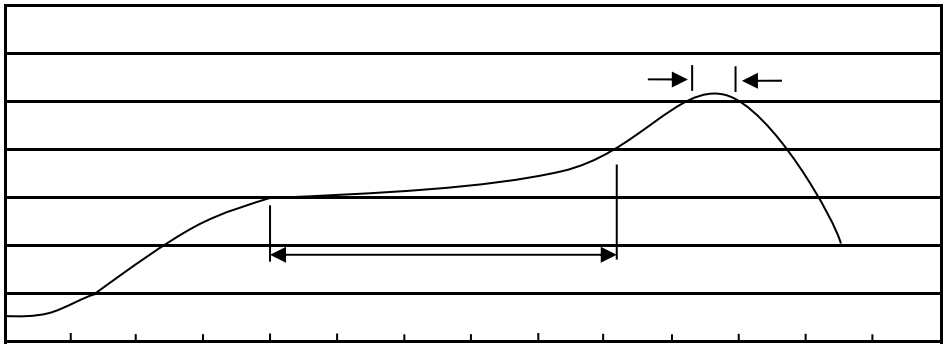


Q

Note:

BR:	Company Code
Q:	Automobile halogen-free product Code
035N10SH:	Product Type Code
****:	Lot No. Code, code change with Lot No

Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

1	150 200 60 120sec;	1.Preheating:150~200 , Time:60~120sec.
2	255 5 5 0.5sec;	2.Peak Temp.:255 5 , Duration:5 0.5sec.
3	2 10 /sec.	3. Cooling Speed: 2~10 /sec.

260 5 10 1 sec. Temp.:260±5 Time:10±1 sec

/ REEL

Package Type	Units					Dimension		(unit mm³)
TO-263	800	1	800	6	4,800	13″ ×24	360×360×50	380×335×366

/ TUBE

Package Type	Units					Dimension		(unit mm³)
TO-263	50	20	1,000	5	5,000	532×33×7.0	555×164×50	575×290×180